

N-Channel Enhancement-Mode Vertical DMOS FET

Features

- Low threshold 1.6V max.
- High input impedance
- Low input capacitance 130pF typical
- Fast switching speeds
- Low on-resistance guaranteed at V_{GS} = 2, 3, and 5V
- Free from secondary breakdown
- Low input and output leakage

Applications

- Logic level interfaces ideal for TTL and CMOS
- Solid state relays
- Battery operated systems
- Photo voltaic drives
- Analog switches
- General purpose line drivers
- Telecom switches

Ordering Information

General Description

This low threshold, enhancement-mode (normally-off) transistor utilizes a vertical DMOS structure and Supertex's well-proven, silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Product Summary

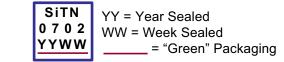
BV_{DSS}/BV_{DGS}	R _{DS(ON)} (max)	l _{D(ON)} (min)	V _{GS(th)} (max)		
20V	1.3Ω	0.5A	1.0V		

Pin Configuration



BV_{DSS}

Product Marking



Package may or may not include the following marks: Si or 🎲

TO-92

 Part Number
 Package Option
 Packing

 TN0702N3-G
 TO-92
 1000/Bag

 TN0702N3-G P002
 1000/Bag
 1000/Bag

 TN0702N3-G P003
 TO-92
 2000/Reel

 TN0702N3-G P013
 TO-92
 2000/Reel

 TN0702N3-G P014
 TO-92
 2000/Reel

-G denotes a lead (Pb)-free / RoHS compliant package. Contact factory for Wafer / Die availablity.

Devices in Wafer / Die form are lead (Pb)-free / RoHS compliant.

Absolute Maximum Ratings

Parameter	Value
Drain-to-source voltage	BV _{DSS}
Drain-to-gate voltage	BV _{DGS}
Gate-to-source voltage	±20V
Operating and storage temperature	-55°C to +150°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

Typical Thermal Resistance

Package	$\boldsymbol{\theta}_{_{ja}}$
TO-92	132°C/W

TN0702

Thermal Characteristics

Package	kage I _D I _D I _D		Power Dissipation @T _c = 25°C		I _{DRM}	
TO-92	530mA	1.0A	1.0W	530mA	1.0A	

Notes:

† I_{D} (continuous) is limited by max rated T_{i} .

Electrical Characteristics ($T_A = 25^{\circ}C$ unless otherwise specified)

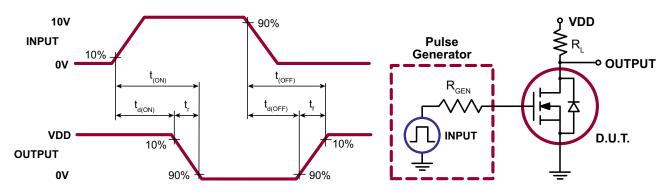
Sym	Parameter	Min	Тур	Max	Units	Conditions
BV _{DSS}	Drain-to-source breakdown voltage	20	-	-	V	V _{GS} = 0V, I _D = 1.0mA
V _{GS(th)}	Gate threshold voltage	0.5	0.8	1.0	V	$V_{GS} = V_{DS}, I_{D} = 1.0 \text{mA}$
$\Delta V_{GS(th)}$	Change in $V_{GS(th)}$ with temperature	-	-	-4.0	mV/ºC	$V_{GS} = V_{DS}, I_{D} = 1.0 \text{mA}$
I _{GSS}	Gate body leakage	-	-	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
		-	-	100	nA	V_{GS} = 0V, V_{DS} = Max Rating
I _{DSS}	Zero gate voltage drain current	-	-	100	μA	$V_{DS} = 0.8$ Max Rating, $V_{GS} = 0V$, $T_A = 125^{\circ}C$
I _{D(ON)}	On-state drain current	0.5	1.0	-	Α	$V_{GS} = V_{DS} = 5.0V$
	Static drain-to-source on-state resistance		4.0	5.0	Ω	V_{GS} = 2.0V, I_{D} = 50mA
R _{DS(ON)}			1.9	2.5		$V_{GS} = 3.0V, I_{D} = 200mA$
		-	1.0	1.3		V _{GS} = 5.0V, I _D = 500mA
$\Delta R_{DS(ON)}$	Change in $R_{DS(ON)}$ with temperature	-	-	0.75	%/°C	V _{GS} = 5.0V, I _D = 500mA
G _{FS}	Forward transductance	100	500	-	mmho	V _{DS} = 5.0V, I _D = 500mA
C _{ISS}	Input capacitance	-	130	200		V _{GS} = 0V,
C _{oss}	Common source output capacitance	-	70	125	pF	V _{DS} = 20V,
C _{RSS}	Reverse transfer capacitance	-	30	60		f = 1.0MHz
t _{d(ON)}	Turn-on delay time	-	-	20		
t _r	Rise time	-	-	20	ns	$V_{DD} = 20V,$
t _{d(OFF)}	Turn-off delay time	-	-	30		$I_{D} = 0.5A,$ $R_{GEN} = 25\Omega$
t,	Fall time	-	-	20		GEN
V _{SD}	Diode forward voltage drop	-	-	1.0	V	V _{GS} = 0V, I _{SD} = 0.5A

Notes:

1. All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)

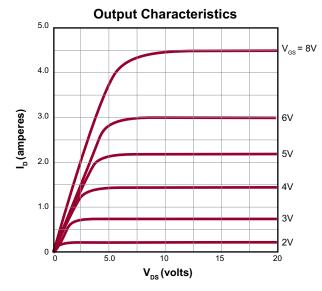
2. All A.C. parameters sample tested.

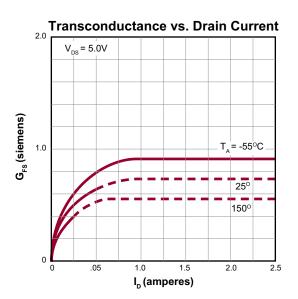
Switching Waveforms and Test Circuit



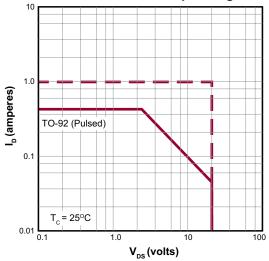
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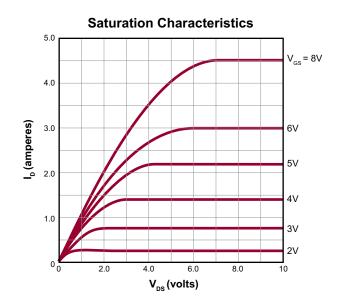
Typical Performance Curves



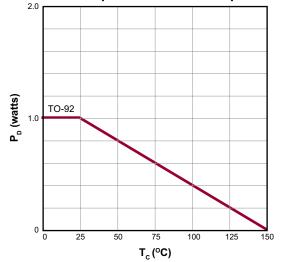


Maximum Rated Safe Operating Area

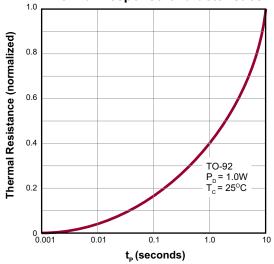




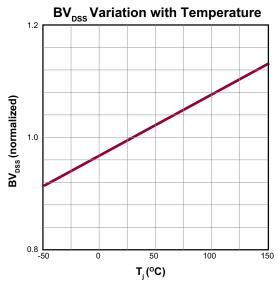
Power Dissipation vs. Case Temperature



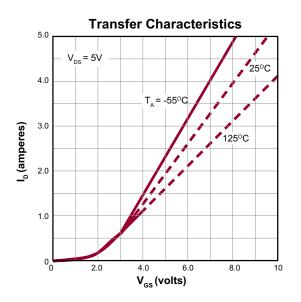
Thermal Response Characteristics



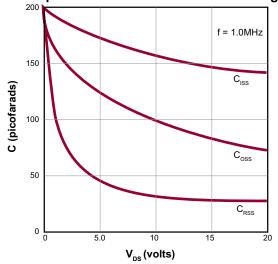
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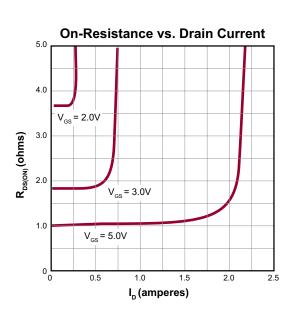


Typical Performance Curves (cont.)

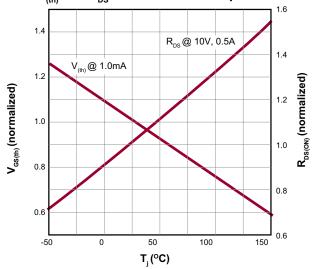




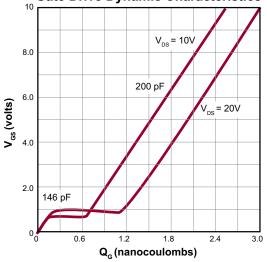




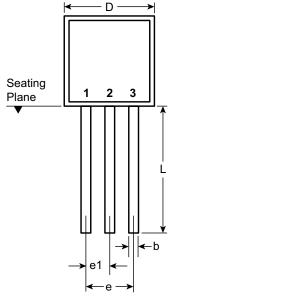
 $V_{\mbox{\tiny (th)}}$ and $R_{\mbox{\tiny DS}}$ Variation with Temperature

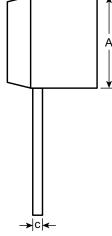






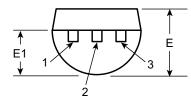
3-Lead TO-92 Package Outline (N3)





Front View

Side View



Bottom View

Symbol		Α	b	С	D	E	E1	е	e1	L
	MIN	.170	.014†	.014†	.175	.125	.080	.095	.045	.500
Dimensions (inches)	NOM	-	-	-	-	-	-	-	-	-
	MAX	.210	.022†	.022†	.205	.165	.105	.105	.055	.610*

JEDEC Registration TO-92.

* This dimension is not specified in the JEDEC drawing.

† This dimension differs from the JEDEC drawing.

Drawings not to scale.

Supertex Doc.#: DSPD-3TO92N3, Version E041009.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <u>http://www.supertex.com/packaging.html</u>.)

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